

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1107	(438/514).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 15:24
S2	128	S1 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 15:25
S3	128	S1 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:13
S4	24	S1 and (flash near5 memor\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 15:27
S5	735	(438/522).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 16:12
S6	37	S5 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:22
S7	134	S5 and dopant	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:22
S8	739	(438/527).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 16:22

S9	122	S8 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:58
S10	942	(438/530).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 16:58
S11	99	S10 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 17:06
S12	913	(438/542).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 17:06
S13	49	S12 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 17:10
S14	434	(438/549).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 17:10
S15	30	S14 and memor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 17:16
S16	116	(438/560).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/23 09:59
S17	6	("5160996" "5283200" "5393683" "5474940" "5559050" "5898007").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/22 18:12
S18	6	("6251718").URPN.	USPAT	OR	ON	2005/08/22 18:18

S19	502507	memory	USPAT	OR	ON	2005/08/22 18:19
S20	156326	S19 and ((read adj only adj memory) rom)	USPAT	OR	ON	2005/08/22 18:20
S21	846	S20 and flas	USPAT	OR	ON	2005/08/22 18:21
S22	29596	S20 and flash	USPAT	OR	ON	2005/08/22 18:21
S23	21337	S20 and (flash near3 memory)	USPAT	OR	ON	2005/08/22 18:21
S24	7851	S23 and ((periphe\$3 logi\$3) and (cell core))	USPAT	OR	ON	2005/08/22 19:06
S25	794	S24 and ((ion dopant) near5 implant\$4)	USPAT	OR	ON	2005/08/23 09:00
S26	1630	S24 and (ion dopant)	USPAT	OR	ON	2005/08/23 08:55
S27	1356	S26 and (heat thermal diffusion anneal treatment)	USPAT	OR	ON	2005/08/22 18:26
S28	1338	S26 and (heat thermal diffusion anneal)	USPAT	OR	ON	2005/08/23 08:56
S29	0	S28 and (cumulat\$4 near5 anneal)	USPAT	OR	ON	2005/08/23 08:55
S30	77	S28 and (cumulat\$4)	USPAT	OR	ON	2005/08/22 18:28
S31	1113	S28 and (source and drain)	USPAT	OR	ON	2005/08/22 18:56
S32	164	S28 and (periphery near3 (region area))	USPAT	OR	ON	2005/08/22 18:30
S33	135	S31 and ((decreas\$3 reduc\$3 smaller) near5 size near5 memory near5 cell)	USPAT	OR	ON	2005/08/22 19:06
S34	478	S28 and ((periphe\$3 logi\$3) near4 (region area))	USPAT	OR	ON	2005/08/23 08:53
S35	52	S34 and ((decreas\$3 reduc\$3 shrink\$3 smaller) near5 size near5 memory near5 cell)	USPAT	OR	ON	2005/08/22 19:08
S36	99307	flash near6 memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 08:53
S38	1302	S36 and (((periphe\$3 logi\$3) near4 (region area)) and ((cell core) near4 (region area)))	USPAT	OR	ON	2005/08/23 15:55
S39	2375	S36 and ((periphe\$3 logi\$3) near4 (region area))	USPAT	OR	ON	2005/08/23 08:55
S40	1031	S39 and (ion dopant)	USPAT	OR	ON	2005/08/23 08:55
S41	0	S40 and (cumulat\$4 near5 anneal)	USPAT	OR	ON	2005/08/23 08:55
S42	904	S40 and (heat thermal diffusion anneal)	USPAT	OR	ON	2005/08/23 08:59

S43	36	S40 and ((different simulata\$6 each) near6 (heat thermal diffusion anneal))	USPAT	OR	ON	2005/08/23 09:04
S44	918	S38 and (heat thermal diffusion anneal)	USPAT	OR	ON	2005/08/23 08:59
S45	466	S44 and ((ion dopant) near5 implant\$4)	USPAT	OR	ON	2005/08/23 09:00
S46	58	S40 and ((different simulata\$6 each separate) near6 (heat thermal diffusion anneal))	USPAT	OR	ON	2005/08/23 09:18
S47	119	S40 and ((different simulata\$6 each separa\$4 plural\$3) near6 (heat thermal diffusion anneal))	USPAT	OR	ON	2005/08/23 09:19
S48	87	S40 and ((different simulata\$6 each separa\$4 plural\$3) near4 (heat thermal diffusion anneal))	USPAT	OR	ON	2005/08/23 09:54
S49	97	S40 and ((different simulata\$6 each separa\$4 plural\$3 several) near4 (heat thermal diffusion anneal))	USPAT	OR	ON	2005/08/23 09:54
S50	823590	(another second further) same (anneal\$3 thermal\$2 heat\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 15:49
S51	904021	(another second further) same (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 15:49
S52	273305	(another second further) near5 (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 15:50
S53	239511	(another second further) near4 (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 15:50
S54	196935	(another second further) near3 (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:00

S55	26580	S53 and (memory rom (read adj only adj memory) dram sram)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:01
S56	11923	S55 and (dop\$3 impurit\$3 ion ionized)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:02
S57	422	S56 and (((periphe\$3 logi\$3) near4 (region area)) and ((cell core) near4 (region area)))	USPAT	OR	ON	2005/08/23 16:02
S58	371	S56 and (((periphe\$3 logi\$3) near3 (region area)) and ((cell core) near3 (region area)))	USPAT	OR	ON	2005/08/23 15:59
S59	142547	(another second further) near2 (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:01
S60	79812	(another second further) near (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S61	16139	S59 and (memory rom (read adj only adj memory) dram sram)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S62	9100	S60 and (memory rom (read adj only adj memory) dram sram)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:01
S63	4118	S62 and (dop\$3 impurit\$3 ion ionized)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S64	123	S63 and (((periphe\$3 logi\$3) near4 (region area)) and ((cell core) near4 (region area)))	USPAT	OR	ON	2005/08/23 16:08

S65	79812	(another second further) near1 (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:04
S66	63530	(another second further) adj (anneal\$3 thermal\$2 heat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S67	7208	S66 and (memory rom (read adj only adj memory) dram sram)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S68	3326	S67 and (dop\$3 impurit\$3 ion ionized)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 16:08
S69	107	S68 and (((periphe\$3 logi\$3) near4 (region area)) and ((cell core) near4 (region area)))	USPAT	OR	ON	2005/08/23 16:09
S70	2	("20020102793").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/24 13:26